Crystal Growth of Molybdenum Oxides by Chemical Transport

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Single crystals of MoO$_2$, MoO$_3$, and Mo$_n$O$_{3n-1}$ ($n=4, 8, 9$) were grown by chemical transport using TeCl$_4$ as transport agent. The electrical resistivities of the grown crystals were measured from liquid nitrogen temperature to room temperature.

I INTRODUCTION

There are many intermediate oxides such as Mo$_n$O$_{3n-1}$ between MoO$_2$ and MoO$_3$. The phase diagram of the Mo-O system$^{1)}$ showed that there are two distinct oxides, Mo$_5$O$_{11}$ and Mo$_9$O$_{26}$ between MoO$_2$ and MoO$_3$. Kihlborg$^{2)}$ recognized five compounds as the intermediate oxides (Mo$_n$O$_{3n-1}$), that is, Mo$_4$O$_{11}$, Mo$_6$O$_{14}$, Mo$_8$O$_{23}$, Mo$_{10}$O$_{26}$ and Mo$_{12}$O$_{39}$, of which Mo$_5$O$_{11}$ and Mo$_9$O$_{26}$ are dimorphic. These intermediate oxides are the Magneli phases whose crystal structures can be described on the basis of the ReO$_3$ type.$^{2)}$

Chemical transport in the closed system has been applied to the growth of single crystal of the Magneli phases ($V_nO_{2n-1}$, Ti$_n$O$_{2n-1}$) using TeCl$_4$ as transport agent.$^{3-5)}$ In crystal growth of Magneli phase, oxygen pressure is the important parameter which must be delicately adjusted to control the particular phase grown, because each phase is stable only in the narrow range of oxygen pressure. Authors$^{4-7)}$ recently succeeded in growing single crystals of $V_nO_{2n-1}$ and Ti$_n$O$_{2n-1}$ by the chemical transport which had no need of the procedure of pressure control. The phase of single crystals ($V_nO_{2n-1}$) obtained by this method was all the same as that of source material. Therefore, it was considered that the single crystals of Mo$_n$O$_{3n-1}$ were possible to be grown by the same method. We have much interested in the relation between the phase of source material and that of single crystals obtained.

II EXPERIMENTALS

Synthesis of source materials. Source materials for the chemical transport were synthesized from highly pure molybdenum dioxide and trioxide. Mixtures of MoO$_3$ and MoO$_2$ (3:1 in mole ratio) were pressed and placed in evacuated silica tube. The sealed tubes were heated at 550°C for 14 days in preparation of monoclinic Mo$_5$O$_{11}$ and at 650°C for 5 days in preparation of orthorhombic Mo$_9$O$_{26}$.

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The products were confirmed as a single phase by X-ray diffraction. Powders of \( \text{Mo}_8\text{O}_{23} \) and \( \text{Mo}_9\text{O}_{26} \) were prepared from \( \text{MoO}_3 \) and \( \text{Mo}_4\text{O}_{11} \). The sealed tubes containing the mixture of \( \text{MoO}_3 \) and \( \text{Mo}_4\text{O}_{11} \) (4:1 in mole ratio) were heated at 700°C for 3 days in preparation of \( \text{Mo}_8\text{O}_{23} \). The mixtures of \( \text{MoO}_3 \) and \( \text{Mo}_4\text{O}_{11} \) (5:1 in mole ratio) in the sealed tube were heated at 750°C for 2 days to product monoclinic \( \text{Mo}_8\text{O}_{23} \) and at 700°C for 3 days to product triclinic \( \text{Mo}_9\text{O}_{26} \). These products were confirmed as a single phase by X-ray diffraction.

**Chemical transport.** The sealed tube for the chemical transport was prepared by the follows. Powder of molybdenum oxide (2 grams) was loaded at the end of transparent silica tube of 13 mm in diameter and 170 mm in length. \( \text{TeCl}_4 \) powder was added as transport agent into the silica tube. This procedure performed in a dry box to prevent \( \text{TeCl}_4 \) from deliquescence. After the tube was evacuated to \( 10^{-6} \) Torr, it was sealed off. The tube was kept in the horizontal electric furnace, where the source zone with the source material was heated at higher temperature and the crystallization zone at lower temperature. After the transport, the tube was quenched in water. In order to measure the transport rate, the crystals obtained at the crystallization zone were weighed.

**Characterization of crystal.** The crystals were identified by the X-ray powder method. Laue X-ray pictures were taken to confirm them to be single crystals. The measurement of electrical resistivity was carried out by means of four point method using a d.c. potentiometer.

### III RESULTS

Table I shows the representative transport conditions for the growth of large

<table>
<thead>
<tr>
<th>Source materials (2 grams)</th>
<th>Temperature gradient (deg/degC)</th>
<th>( \text{TeCl}_4 ) (mg/cc)</th>
<th>Transport time (hr)</th>
<th>Transport rate (mg/hr)</th>
<th>Transported material</th>
<th>comment</th>
</tr>
</thead>
<tbody>
<tr>
<td>( \text{MoO}_2 )</td>
<td>700/630</td>
<td>3.0</td>
<td>70</td>
<td>10.3</td>
<td>( \text{MoO}_2 )</td>
<td>reddish purple polyhedral</td>
</tr>
<tr>
<td>( \text{Mo}<em>4\text{O}</em>{11} ) (ortho.)</td>
<td>690/640</td>
<td>3.0</td>
<td>70</td>
<td>26.4</td>
<td>( \text{Mo}<em>4\text{O}</em>{11} ) (ortho.)</td>
<td>royal purple thin plate</td>
</tr>
<tr>
<td>( \text{Mo}<em>4\text{O}</em>{11} ) (ortho.)</td>
<td>650/560</td>
<td>3.0</td>
<td>50</td>
<td>31.0</td>
<td>( \text{Mo}<em>4\text{O}</em>{11} ) (monocli.)</td>
<td>royal purple thin plate</td>
</tr>
<tr>
<td>( \text{Mo}<em>4\text{O}</em>{11} ) (monocli.)</td>
<td>580/500</td>
<td>3.0</td>
<td>50</td>
<td>26.6</td>
<td>( \text{Mo}<em>4\text{O}</em>{11} ) (monocli.)</td>
<td>royal purple thin plate</td>
</tr>
<tr>
<td>( \text{Mo}<em>9\text{O}</em>{23} )</td>
<td>750/730</td>
<td>0.5</td>
<td>71</td>
<td>8.8</td>
<td>( \text{Mo}<em>9\text{O}</em>{23} )</td>
<td>purplish black</td>
</tr>
<tr>
<td>( \text{Mo}<em>9\text{O}</em>{26} ) (monocli.)</td>
<td>770/760</td>
<td>0.5</td>
<td>69</td>
<td>6.1</td>
<td>( \text{Mo}<em>9\text{O}</em>{26} ) (monocli.)</td>
<td>black</td>
</tr>
<tr>
<td>( \text{Mo}<em>9\text{O}</em>{26} ) (monocli.)</td>
<td>770/745</td>
<td>0.5</td>
<td>70</td>
<td>16.7</td>
<td>( \text{Mo}<em>9\text{O}</em>{26} ) (tricli.)</td>
<td>black needle</td>
</tr>
<tr>
<td>( \text{Mo}<em>9\text{O}</em>{26} ) (tricli.)</td>
<td>750/730</td>
<td>0.5</td>
<td>70</td>
<td>13.8</td>
<td>( \text{Mo}<em>9\text{O}</em>{26} ) (tricli.)</td>
<td>black needle</td>
</tr>
<tr>
<td>( \text{MoO}_3 )</td>
<td>650/600</td>
<td>3.0</td>
<td>74</td>
<td>11.9</td>
<td>( \text{MoO}_3 )</td>
<td>light yellow needle</td>
</tr>
</tbody>
</table>

(331)
crystals, the transport rate and the phases of obtained crystals. The composition of single crystals obtained was the same as that of source material. However, the phase of single crystals of Mo$_{40}$O$_{11}$ and Mo$_{90}$O$_{26}$ depended on the temperature of the crystallization zone, independently of the phase of source material. It was reported by Kihlborg$^2$ that the formation temperature by solid state reaction is 620$\sim$680°C for orthorhombic Mo$_{40}$O$_{11}$, 500$\sim$620°C for monoclinic Mo$_{40}$O$_{11}$, 600$\sim$780°C for monoclinic Mo$_{90}$O$_{26}$ and 750$\sim$780°C for triclinic Mo$_{90}$O$_{26}$. Formation temperature of single crystals of each phase was the same. The photographs of some typical crystals are shown in Fig. 1$\sim$8. Single crystals of MoO$_{2}$ were polyhedral and about 2 mm in size, as shown in Fig. 1. Single crystals of Mo$_{40}$O$_{11}$ shown in Fig. 2 and 3 were thin plate like with well-developed crystal face of (100). Developed crystal face of single crystal is (010) plane for Mo$_{90}$O$_{26}$ (monoclinic) and monoclinic Mo$_{90}$O$_{26}$. Single crystals of triclinic Mo$_{90}$O$_{26}$ were simultaneously grown at source zone and crystallization zone, as shown in Fig. 6 and 7 because temperature difference between the source zone and the crystallization zone was very small. Transport of
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Fig. 5 Triclinic Mo₉O₂₆ crystals

Fig. 6 Monoclinic Mo₉O₂₆ crystals grown at crystallization zone

Fig. 7 Monoclinic Mo₉O₂₆ crystals grown at source zone

Fig. 8 MoO₃ crystals

Fig. 9 Electrical resistivity-temperature curves of Mo₉O₂₆₋₁ single crystals
MoO₃ occurred without transport agent TeCl₄. This may be due to vaporization of MoO₃. The value of transport rate of MoO₃ in Table I shows the subtraction of the data due to vaporization of MoO₃ from the experimental data using TeCl₄.

Electrical resistivities of as-grown single crystals were measured from liquid nitrogen temperature to room temperature. Figure 9 shows the results of the electrical resistivity measurement. Intermediate oxides except triclinic Mo₅O₁₆ were suggested to be metallic conductive in consideration of the value and the temperature dependence of resistivity. Triclinic Mo₅O₁₆ showed semiconduction with the activation energy of 0.29 eV.

REFERENCES